Document Number: MRF8P29300H
Rev. 0, 2/2011

RoHS

RF Power Field Effect Transistors

N-Channel Enhancement-Mode Lateral MOSFETs

MRF8P29300HR6
MRF8P29300HSR6

2700-2900 MHz, 320 W, 30 V
LATERAL N-CHANNEL
BROADBAND
RF POWER MOSFETs

RF Power transistors designed for applications operating at frequencies between 2700 and 2900 MHz. These devices are suitable for use in pulsed applications.

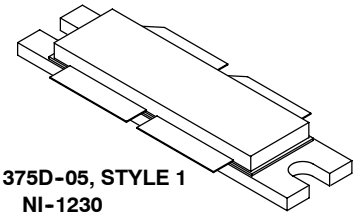
- Typical Pulsed Performance: V_{DD} = 30 Volts, I_{DQ} = 100 mA

Signal Type	P_{out} (W)	f (MHz)	G_{ps} (dB)	η_D (%)	IRL (dB)
Pulsed (100 μsec, 10% Duty Cycle)	320 Peak	2900	13.3	50.5	-17

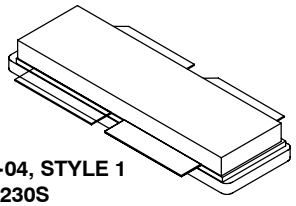
- Capable of Handling 10:1 VSWR, @ 32 Vdc, 2900 MHz, 320 Watts Peak Power, 300 μsec, 10% Duty Cycle (3 dB Input Overdrive from Rated P_{out})

Features

- Characterized with Series Equivalent Large-Signal Impedance Parameters
- Internally Matched for Ease of Use
- Qualified Up to a Maximum of 32 V_{DD} Operation
- Integrated ESD Protection
- Designed for Push-Pull Operation
- Greater Negative Gate-Source Voltage Range for Improved Class C Operation
- RoHS Compliant
- In Tape and Reel. R6 Suffix = 150 Units, 56 mm Tape Width, 13 inch Reel. For R5 Tape and Reel option, see p. 15.

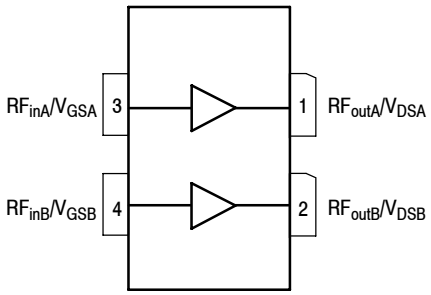


CASE 375D-05, STYLE 1
NI-1230
MRF8P29300HR6



CASE 375E-04, STYLE 1
NI-1230S
MRF8P29300HSR6

PARTS ARE PUSH-PULL



(Top View)

Figure 1. Pin Connections

Table 1. Maximum Ratings

Rating	Symbol	Value	Unit
Drain-Source Voltage	V_{DSS}	-0.5, +65	Vdc
Gate-Source Voltage	V_{GS}	-6.0, +10	Vdc
Storage Temperature Range	T_{stg}	-65 to +150	°C
Case Operating Temperature	T_C	150	°C
Operating Junction Temperature (1,2)	T_J	225	°C

Table 2. Thermal Characteristics

Characteristic	Symbol	Value (2,3)	Unit
Thermal Resistance, Junction to Case	$Z_{\theta JC}$		°C/W
Case Temperature 61°C, 320 W Pulsed, 300 μsec Pulse Width, 10% Duty Cycle, 100 mA, 2900 MHz		0.06	
Case Temperature 69°C, 320 W Pulsed, 500 μsec Pulse Width, 20% Duty Cycle, 100 mA, 2900 MHz		0.10	

1. Continuous use at maximum temperature will affect MTTF.
2. MTTF calculator available at http://www.freescale.com/rf. Select Software & Tools/Development Tools/Calculators to access MTTF calculators by product.
3. Refer to AN1955, *Thermal Measurement Methodology of RF Power Amplifiers.* Go to http://www.freescale.com/rf. Select Documentation/Application Notes - AN1955.

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freescale semiconductor

Table 3. ESD Protection Characteristics

Test Methodology	Class
Human Body Model (per JESD22-A114)	2 (Minimum)
Machine Model (per EIA/JESD22-A115)	A (Minimum)
Charge Device Model (per JESD22-C101)	IV (Minimum)

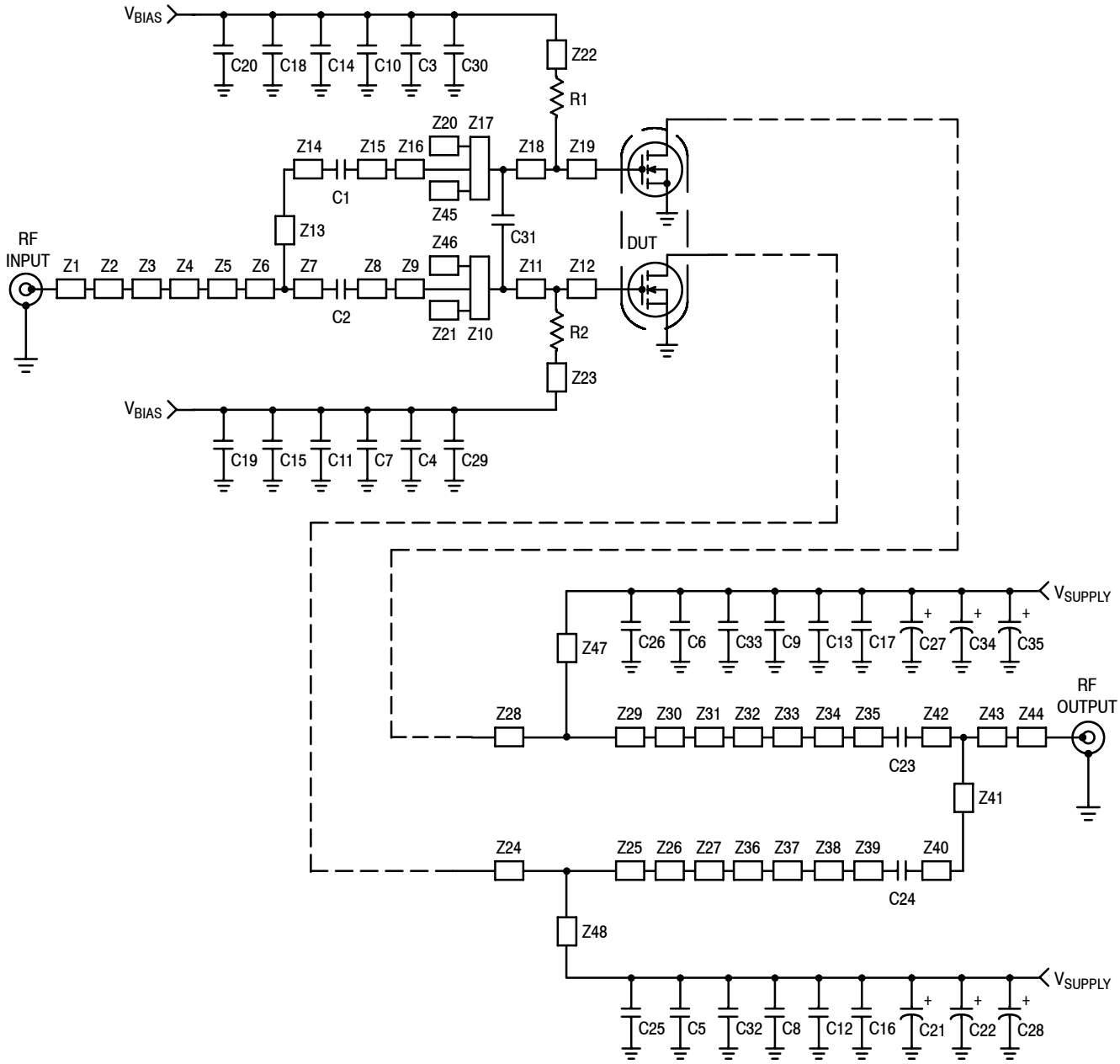
Table 4. Electrical Characteristics (T_A = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Typ	Max	Unit
Off Characteristics (1)					
Gate-Source Leakage Current (V_{GS} = 5 Vdc, V_{DS} = 0 Vdc)	I_{GSS}	—	—	1	μAdc
Zero Gate Voltage Drain Leakage Current (V_{DS} = 30 Vdc, V_{GS} = 0 Vdc)	I_{DSS}	—	—	1	μAdc
Zero Gate Voltage Drain Leakage Current (V_{DS} = 65 Vdc, V_{GS} = 0 Vdc)	I_{DSS}	—	—	10	μAdc
On Characteristics					
Gate Threshold Voltage (1) (V_{DS} = 10 Vdc, I_D = 345 μAdc)	$V_{GS(th)}$	1.0	1.9	2.5	Vdc
Gate Quiescent Voltage (2) (V_{DD} = 30 Vdc, I_D = 100 mAdc, Measured in Functional Test)	$V_{GS(Q)}$	1.5	2.3	3.0	Vdc
Drain-Source On-Voltage (1) (V_{GS} = 10 Vdc, I_D = 2 Adc)	$V_{DS(on)}$	0.1	0.18	0.3	Vdc
Dynamic Characteristics (1)					
Reverse Transfer Capacitance (V_{DS} = 30 Vdc ± 30 mV(rms)ac @ 1 MHz, V_{GS} = 0 Vdc)	C_{rss}	—	2.53	—	pF
Output Capacitance (V_{DS} = 30 Vdc ± 30 mV(rms)ac @ 1 MHz, V_{GS} = 0 Vdc)	C_{oss}	—	470	—	pF
Input Capacitance (V_{DS} = 30 Vdc, V_{GS} = 0 Vdc ± 30 mV(rms)ac @ 1 MHz)	C_{iss}	—	264	—	pF
Functional Tests (2) (In Freescale Test Fixture, 50 ohm system) V_{DD} = 30 Vdc, I_{DQ} = 100 mA, P_{out} = 320 W Peak (32 W Avg.), f = 2900 MHz, 100 μsec Pulse Width, 10% Duty Cycle					
Power Gain	G_{ps}	12.0	13.3	15.0	dB
Drain Efficiency	η_D	47.0	50.5	—	%
Input Return Loss	IRL	—	-17	-9	dB

Typical Pulsed RF Performance (In Freescale 2″x3″ Compact Test Fixture, 50 ohm system) V_{DD} = 30 Vdc, I_{DQ} = 100 mA, P_{out} = 320 W Peak (32 W Avg.), 300 μsec Pulse Width, 10% Duty Cycle

Frequency	G_{ps} (dB)	η_D (%)	IRL (dB)
2700 MHz	13.9	49.3	-11
2800 MHz	14.0	49.8	-18
2900 MHz	13.0	49.6	-15

1. Each side of device measured separately.
2. Measurement made with device in push-pull configuration.



Z1*	0.865″ x 0.065″ Microstrip	Z11, Z18	0.135″ x 0.620″ Microstrip	Z33, Z37	0.112″ x 0.232″ Microstrip
Z2	0.100″ x 0.110″ Microstrip	Z12, Z19	0.120″ x 0.620″ Microstrip	Z34, Z38	0.158″ x 0.152″ Microstrip
Z3	0.075″ x 0.065″ Microstrip	Z13*	0.957″ x 0.065″ Microstrip	Z35, Z39	0.058″ x 0.065″ Microstrip
Z4	0.146″ X 0.111″ Microstrip	Z14	0.495″ x 0.065″ Microstrip	Z40	0.505″ x 0.065″ Microstrip
Z5	0.325″ x 0.204″ Microstrip	Z20, Z21, Z45, Z46	0.055″ x 0.100″ Microstrip	Z41*	0.917″ x 0.065″ Microstrip
Z6	0.224″ x 0.111″ Microstrip	Z22, Z23*	0.554″ x 0.060″ Microstrip	Z42*	0.092″ x 0.065″ Microstrip
Z7*	0.121″ x 0.065″ Microstrip	Z24, Z28	0.202″ x 0.610″ Microstrip	Z43	0.695″ x 0.111″ Microstrip
Z8, Z15	0.030″ x 0.065″ Microstrip	Z25, Z29	0.166″ x 0.560″ Microstrip	Z44*	0.479″ x 0.065″ Microstrip
Z9, Z16	0.284″ x 0.165″ Microstrip	Z26, Z30	0.200″ x 0.622″ Microstrip	Z47, Z48*	0.409″ x 0.100″ Microstrip
Z10, Z17	0.105″ x 0.620″ Microstrip	Z27, Z31	0.088″ x 0.331″ Microstrip		
		Z32, Z36	0.247″ x 0.098″ Microstrip		

* Line length includes microstrip bends

Figure 2. MRF8P29300HR6(HSR6) Test Circuit Schematic

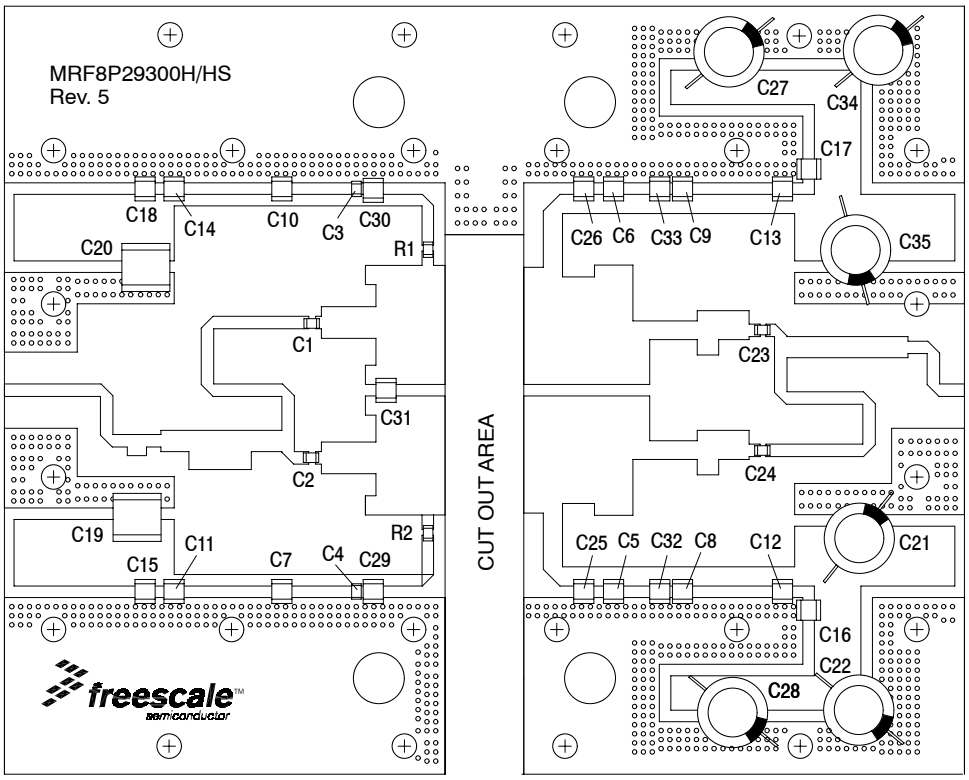
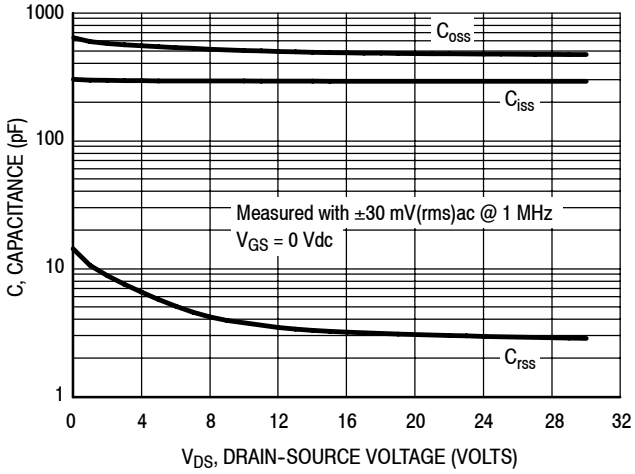


Figure 3. MRF8P29300HR6(HSR6) Test Circuit Component Layout

Table 5. MRF8P29300HR6(HSR6) Test Circuit Component Designations and Values

Part	Description	Part Number	Manufacturer
C1, C2	3.3 pF Chip Capacitors	ATC600F3R3BT250XT	ATC
C3, C4	18 pF Chip Capacitors	ATC600F180JT250XT	ATC
C5, C6, C25, C26, C29, C30	5.1 pF Chip Capacitors	ATC100B5R1BT250XT	ATC
C7, C8, C9, C10	100 pF Chip Capacitors	ATC100B101JT500XT	ATC
C11, C12, C13, C14	1000 pF Chip Capacitors	ATC100B102JT50XT	ATC
C15, C16, C17, C18	1 μF Chip Capacitors	GRM32ER72A105KA01L	Murata
C19, C20	22 μF Chip Capacitors	C5750KF1H226ZT	TDK
C21, C22, C27, C28, C34, C35	470 μF, 63 V Electrolytic Capacitors	MCGPR63V477M16X32-RH	Multicomp
C23, C24	5.1 pF Chip Capacitors	ATC600F5R1CT500XT	ATC
C31	0.5 pF Chip Capacitor	ATC100B0R5BT500XT	ATC
C32, C33	1 μF Chip Capacitors	C3225JB2A105KT	TDK
R1, R2	5 Ω Chip Resistors	CRCW08055R00JNEA	Vishay
PCB	0.030″, ε_r = 3.5	RF35A2	Taconic

TYPICAL CHARACTERISTICS



Note: Each side of device measured separately.

Figure 4. Capacitance versus Drain-Source Voltage

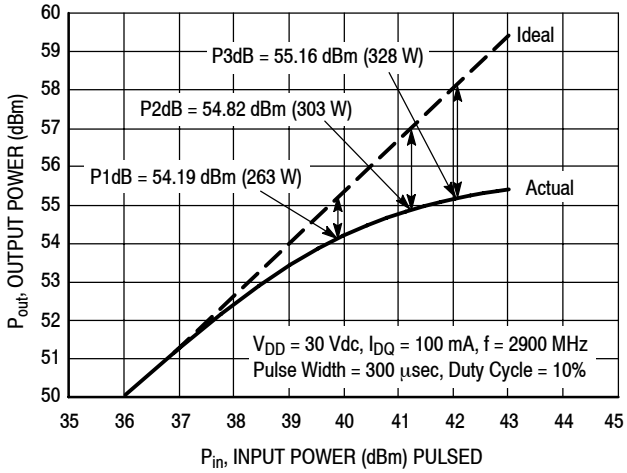


Figure 5. Pulsed Output Power versus Input Power

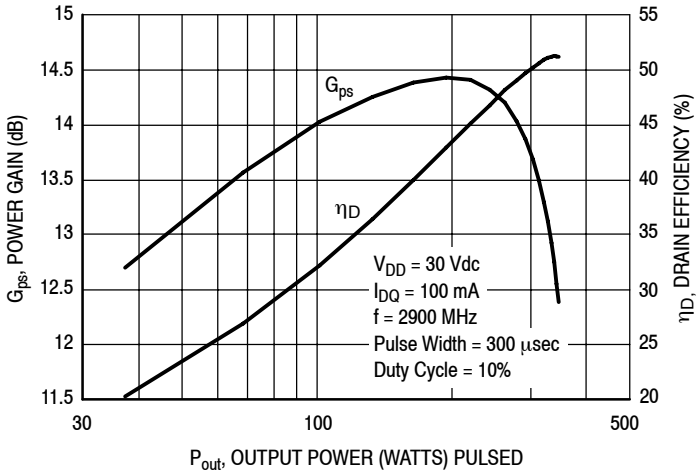


Figure 6. Pulsed Power Gain and Drain Efficiency versus Output Power

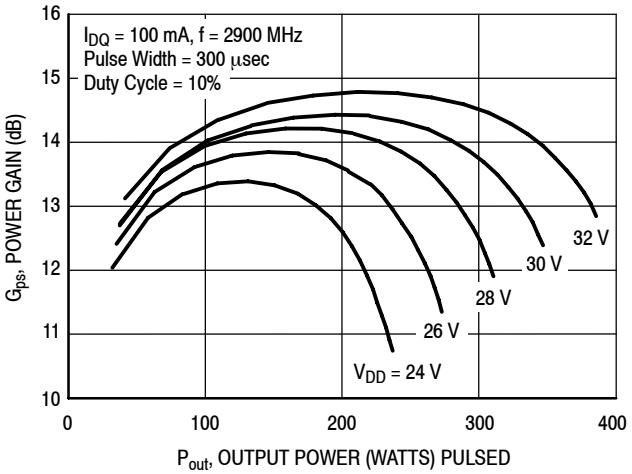


Figure 7. Pulsed Power Gain versus Output Power

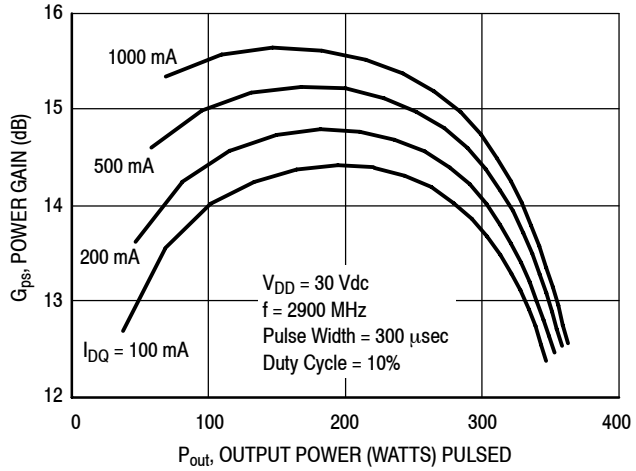


Figure 8. Pulsed Power Gain versus Output Power

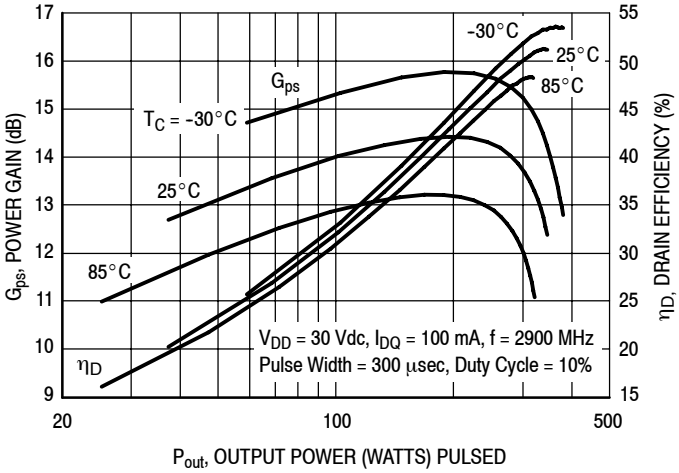


Figure 9. Pulsed Power Gain and Drain Efficiency versus Output Power

TYPICAL CHARACTERISTICS

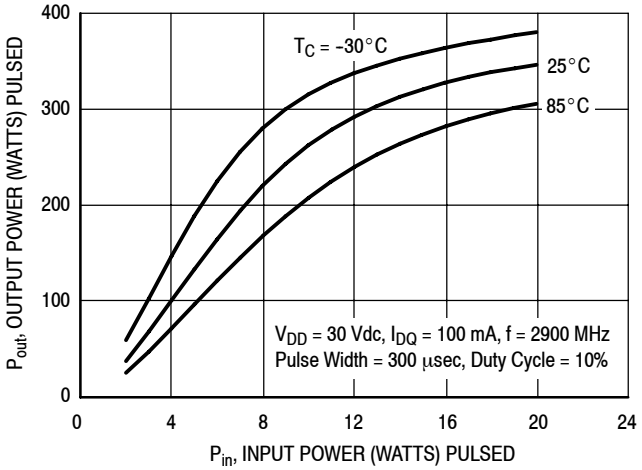


Figure 10. Pulsed Output Power versus Input Power

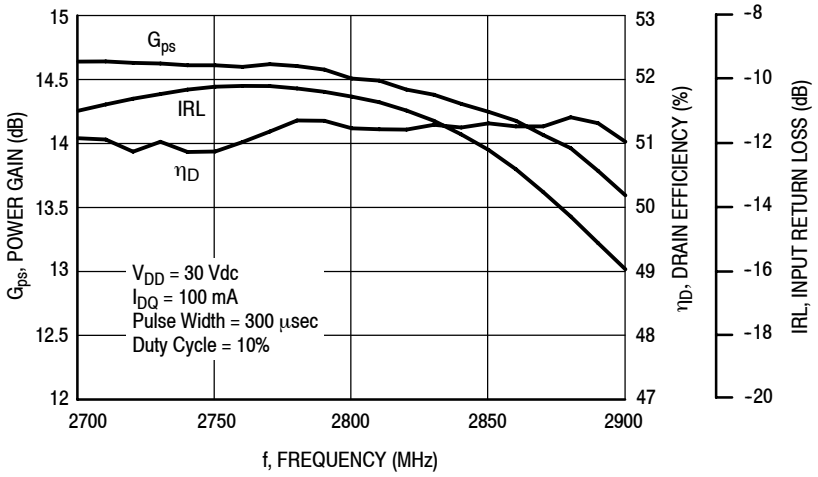
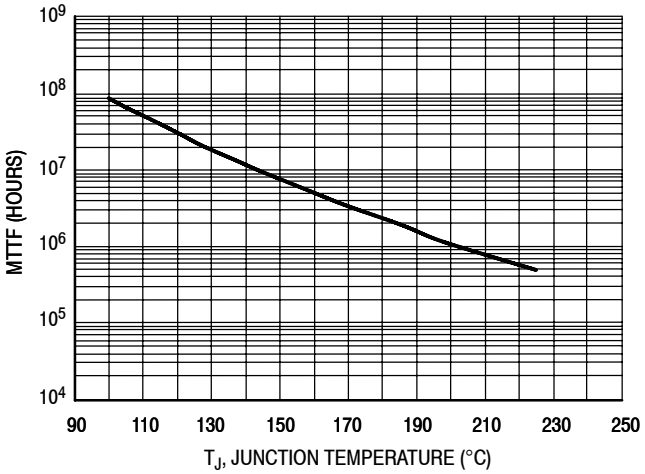


Figure 11. Pulsed Power Gain, Drain Efficiency and Input Return Loss versus Frequency

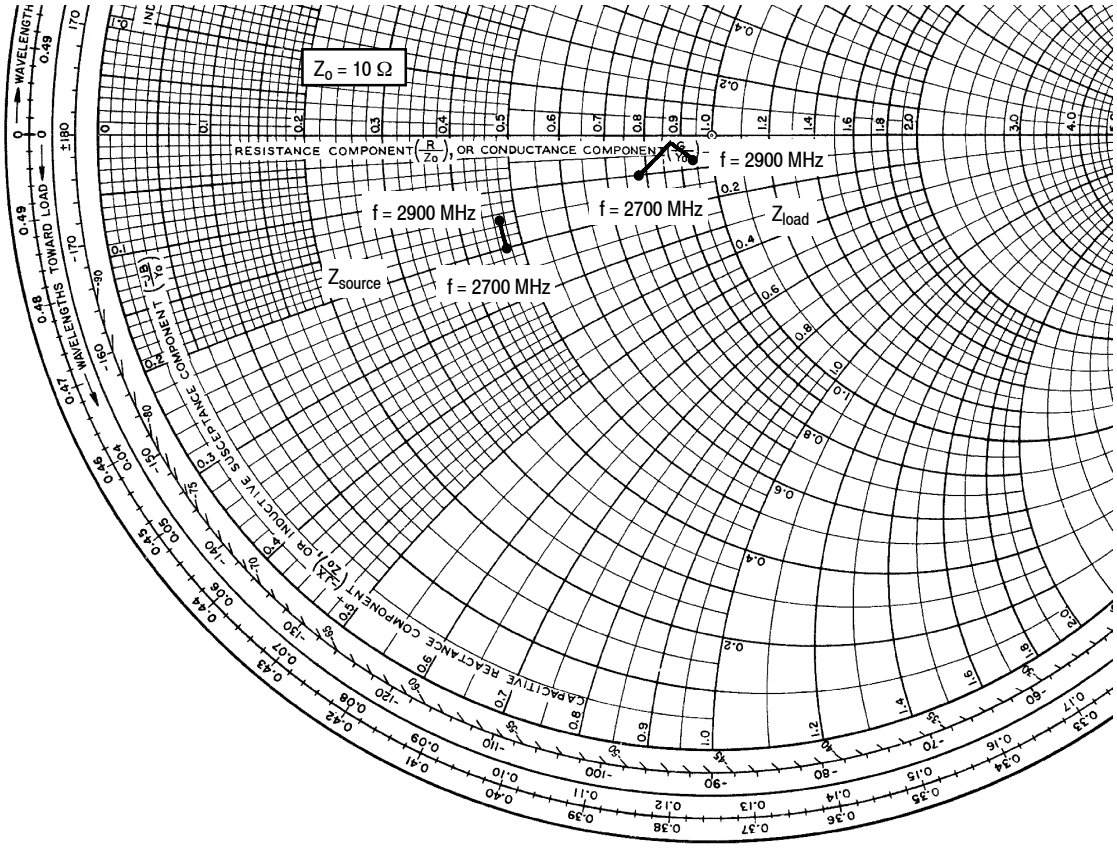
TYPICAL CHARACTERISTICS



This above graph displays calculated MTTF in hours when the device is operated at V_{DD} = 30 Vdc, P_{out} = 320 W Peak, Pulse Width = 300 μsec, Duty Cycle = 10%, and η_D = 45%.

MTTF calculator available at http://www.freescale.com/rf. Select Software & Tools/Development Tools/Calculators to access MTTF calculators by product.

Figure 12. MTTF versus Junction Temperature



V_{DD} = 30 Vdc, I_{DQ} = 100 mA, P_{out} = 320 W Peak

f MHz	Z_{source} Ω	Z_{load} Ω
2700	4.7 – j2.0	7.8 – j1.0
2800	4.7 – j1.7	8.7 – j0.2
2900	4.7 – j1.5	9.4 – j0.7

Z_{source} = Test circuit impedance as measured from gate to gate, balanced configuration.

Z_{load} = Test circuit impedance as measured from drain to drain, balanced configuration.

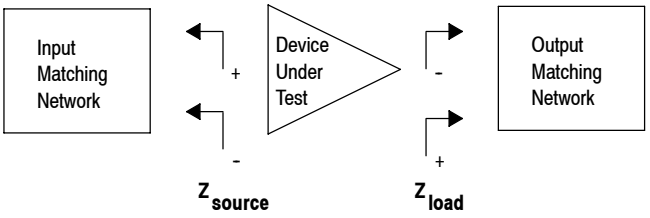


Figure 13. Series Equivalent Source and Load Impedance

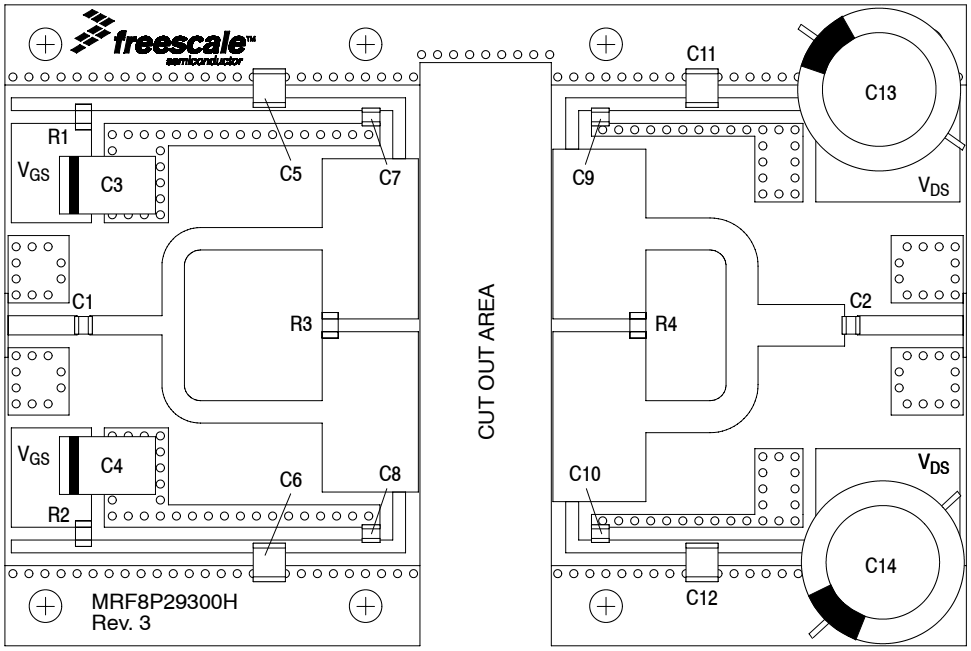


Figure 14. MRF8P29300HR6(HSR6) 2″x3″ Compact Test Circuit Component Layout

Table 6. MRF8P29300HR6(HSR6) 2″x3″ Compact Test Circuit Component Designations and Values

Part	Description	Part Number	Manufacturer
C1, C2	4.7 pF Chip Capacitors	ATC100A4R7BT150XT	ATC
C3, C4	47 μF, 16 V Tantalum Capacitors	T491D476K016AT	Kemet
C5, C6, C11, C12	100 pF Chip Capacitors	ATC100B101JT500XT	ATC
C7, C8, C9, C10	15 pF Chip Capacitors	ATC100A150JT150XT	ATC
C13, C14	470 μF, 63 V Electrolytic Capacitors	MCGPR63V477M13X26-RH	Multicomp
R1, R2, R3, R4	10 Ω Chip Resistors	CRCW120610R0JNEA	Vishay
PCB	0.050″, ε_r = 10.2	RO3010	Rogers

TYPICAL CHARACTERISTICS — 2″x3″ COMPACT TEST FIXTURE

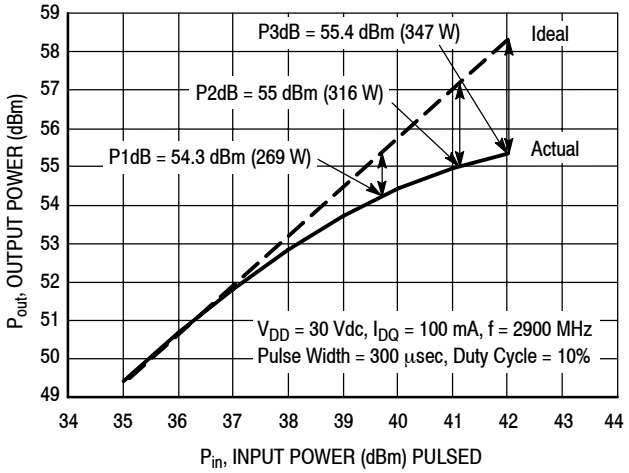


Figure 15. Pulsed Output Power versus Input Power

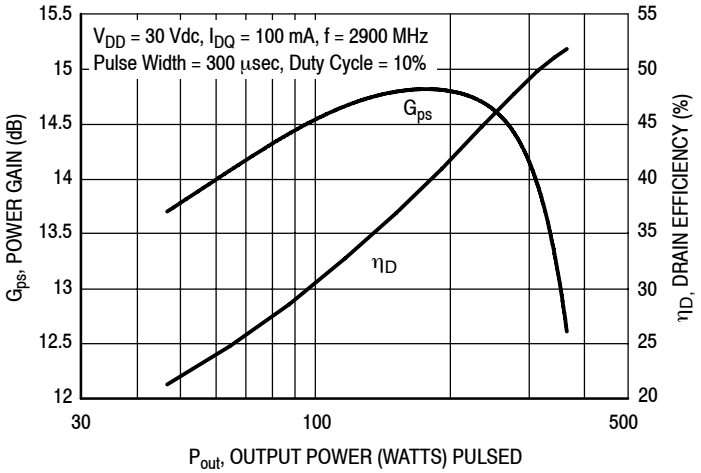


Figure 16. Pulsed Power Gain and Drain Efficiency versus Output Power

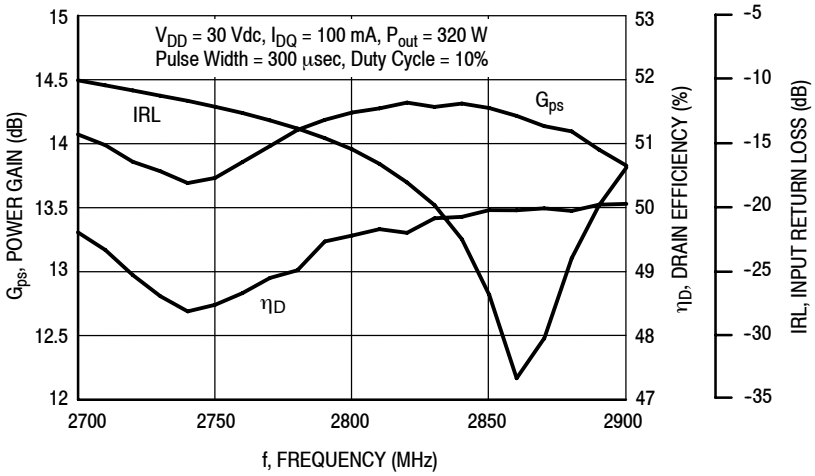
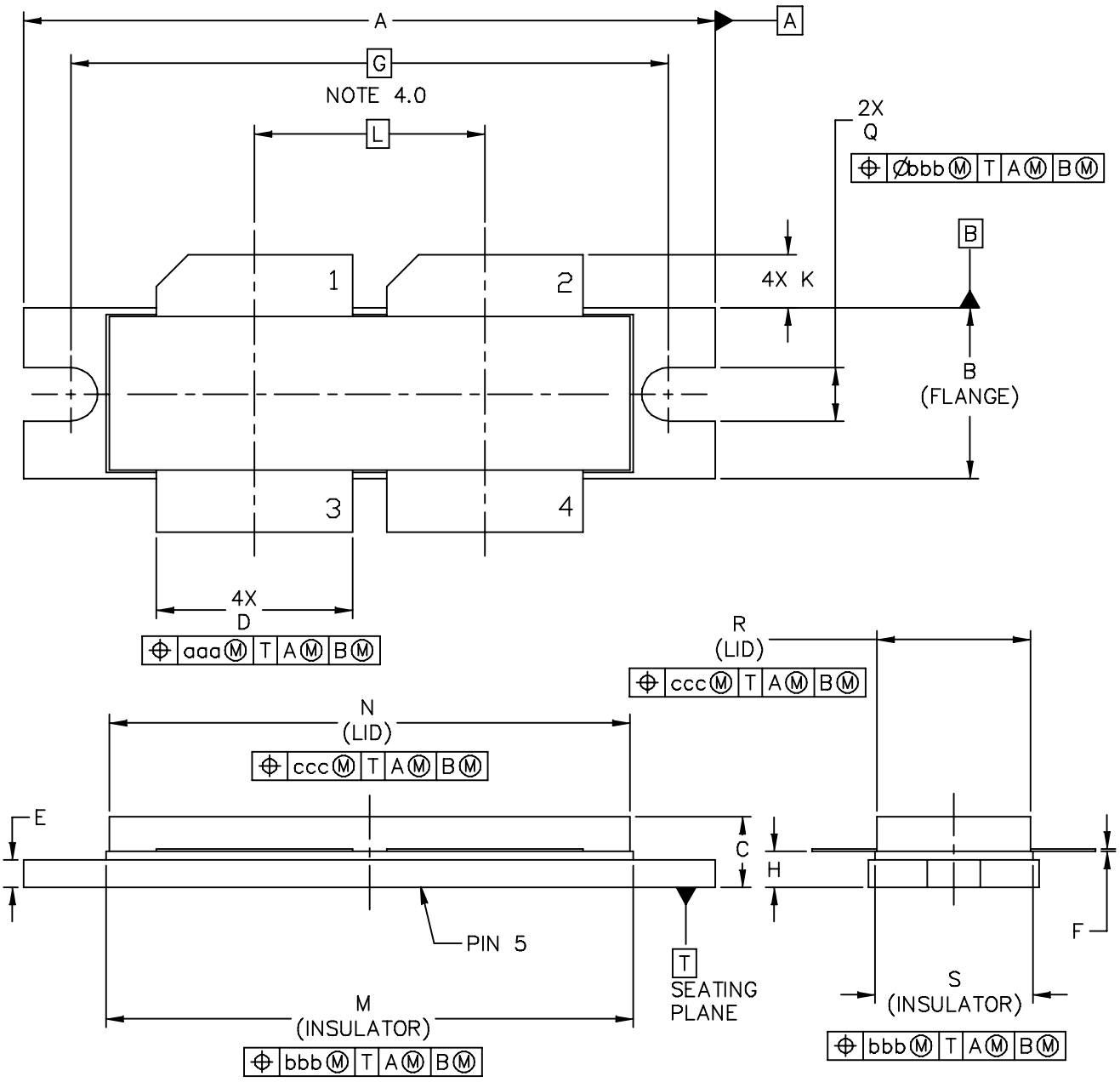


Figure 17. Pulsed Power Gain, Drain Efficiency and Input Return Loss versus Frequency

PACKAGE DIMENSIONS



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TITLE: NI−1230	DOCUMENT NO: 98ASB16977C	REV: E
	CASE NUMBER: 375D−05	31 MAR 2005
	STANDARD: NON−JEDEC	

NOTES:

1. 0 INTERPRET DIMENSIONS AND TOLERANCES
PER ASME Y14. 5M–1994.

2. 0 CONTROLLING DIMENSION: INCH

3. 0 DIMENSION H IS MEASURED . 030 (0. 762)
AWAY FROM PACKAGE BODY.

4. 0 RECOMMENDED BOLT CENTER DIMENSION OF
1. 52 (38. 61) BASED ON M3 SCREW.

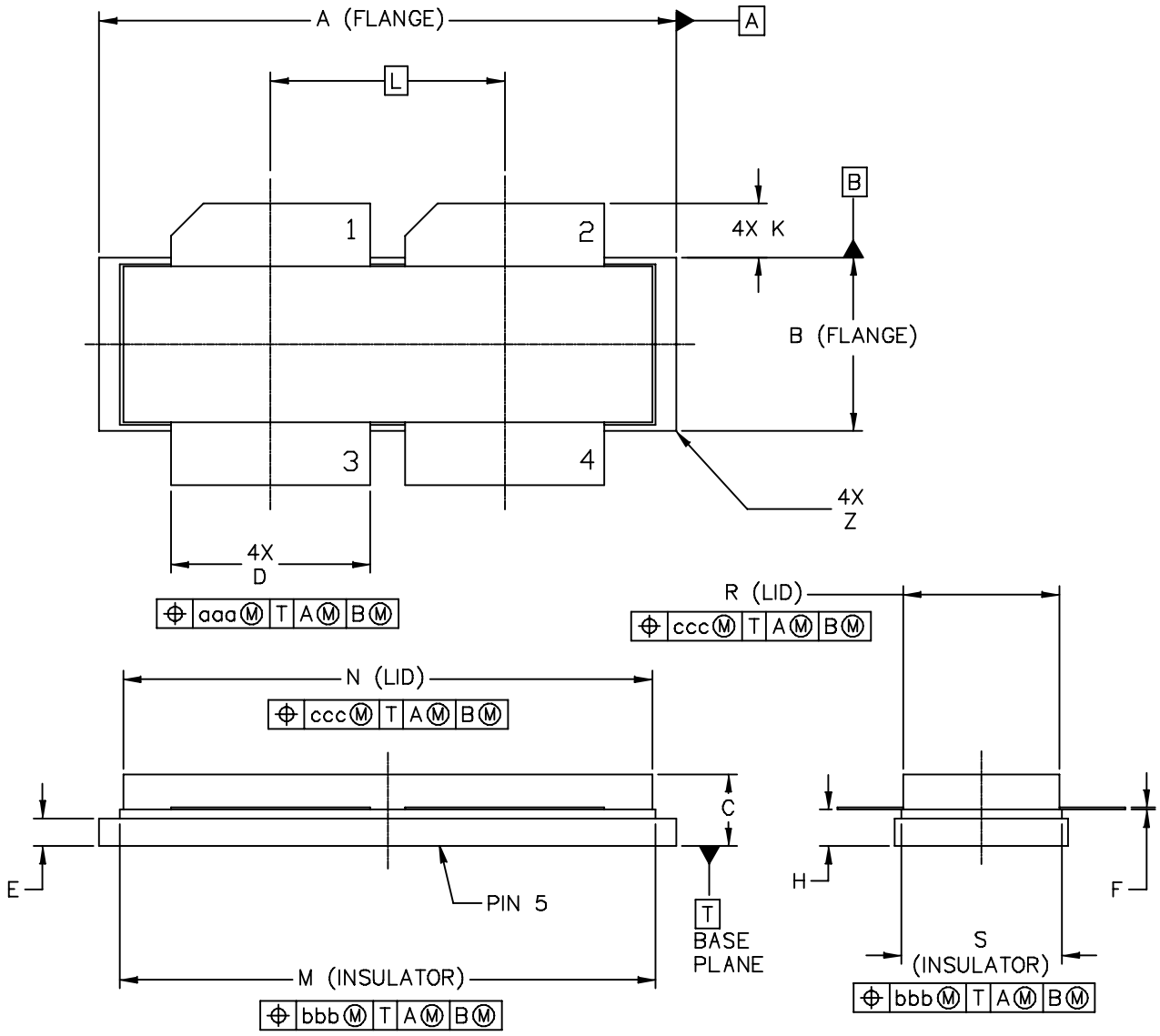
STYLE 1:
PIN 1 – DRAIN
2 – DRAIN
3 – GATE
4 – GATE
5 – SOURCE

DIM	INCH MIN	INCH MAX	MILLIMETER MIN	MILLIMETER MAX	DIM	INCH MIN	INCH MAX	MILLIMETER MIN	MILLIMETER MAX
A	1.615	1.625	41.02	41.28	N	1.218	1.242	30.94	31.55
B	.395	.405	10.03	10.29	Q	.120	.130	3.05	3.3
C	.150	.200	3.81	5.08	R	.355	.365	9.01	9.27
D	.455	.465	11.56	11.81	S	.365	.375	9.27	9.53
E	.062	.066	1.57	1.68					
F	.004	.007	0.1	0.18					
G	1.400 BSC		35.56 BSC		aaa	.013		0.33	
H	.082	.090	2.08	2.29	bbb	.010		0.25	
K	.117	.137	2.97	3.48	ccc	.020		0.51	
L	.540 BSC		13.72 BSC						
M	1.219	1.241	30.96	31.52					

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TITLE:	DOCUMENT NO: 98ASB16977C	REV: E
NI–1230	CASE NUMBER: 375D–05	31 MAR 2005
	STANDARD: NON–JEDEC	



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TITLE: NI−1230S	DOCUMENT NO: 98ARB18247C	REV: F
	CASE NUMBER: 375E−04	05 AUG 2005
	STANDARD: NON−JEDEC	

NOTES:

1. INTERPRET DIMENSIONS AND TOLERANCES PER ASME Y14.5M–1994.

2. CONTROLLING DIMENSION: INCH

3. DIMENSION H IS MEASURED .030 AWAY FROM PACKAGE BODY

STYLE 1:
PIN 1 – DRAIN
2 – DRAIN
3 – GATE
4 – GATE
5 – SOURCE

DIM	INCHES MIN	INCHES MAX	MILLIMETERS MIN	MILLIMETERS MAX	DIM	INCHES MIN	INCHES MAX	MILLIMETERS MIN	MILLIMETERS MAX
A	1.265	1.275	32.13	32.38	R	.355	.365	9.01	9.27
B	.395	.405	10.03	10.29	S	.365	.375	9.27	9.53
C	.150	.200	3.81	5.08	Z	---	.040	---	1.02
D	.455	.465	11.56	11.81					
E	.062	.066	1.57	1.68	aaa	.013		0.33	
F	.004	.007	0.1	0.18	bbb	.010		0.25	
H	.082	.090	2.08	2.29	ccc	.020		0.51	
K	.117	.137	2.97	3.48					
L	.540 BSC		13.72 BSC						
M	1.219	1.241	30.96	31.52					
N	1.218	1.242	30.94	31.55					

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MECHANICAL OUTLINE | PRINT VERSION NOT TO SCALE

TITLE:	DOCUMENT NO: 98ARB18247C	REV: F
NI–1230S	CASE NUMBER: 375E–04	05 AUG 2005
	STANDARD: NON–JEDEC	

PRODUCT DOCUMENTATION AND SOFTWARE

Refer to the following documents and software to aid your design process.

Application Notes

- AN1955: Thermal Measurement Methodology of RF Power Amplifiers

Engineering Bulletins

- EB212: Using Data Sheet Impedances for RF LDMOS Devices

Software

- Electromigration MTTF Calculator
- RF High Power Model
- .s2p File

For Software, do a Part Number search at http://www.freescale.com, and select the “Part Number” link. Go to the Software & Tools tab on the part’s Product Summary page to download the respective tool.

R5 TAPE AND REEL OPTION

R5 Suffix = 50 Units, 56 mm Tape Width, 13 inch Reel.

The R5 tape and reel option for MRF8P29300H and MRF8P29300HS parts will be available for 2 years after release of MRF8P29300H and MRF8P29300HS. Freescale Semiconductor, Inc. reserves the right to limit the quantities that will be delivered in the R5 tape and reel option. At the end of the 2 year period customers who have purchased these devices in the R5 tape and reel option will be offered MRF8P29300H and MRF8P29300HS in the R6 tape and reel option.

REVISION HISTORY

The following table summarizes revisions to this document.

Revision	Date	Description
0	Feb. 2011	• Initial Release of Data Sheet

How to Reach Us:

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